NSN 5961-01-282-3472

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#### **Inclosure Material:**

Plastic

**Overall Length:** 

0.625 inches

## **Overall Height:**

0.190 inches

#### **Overall Width:**

0.420 inches

## **Mounting Facility Quantity:**

1

### **Internal Configuration:**

Junction contact-darlington connected

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220ab

#### **Mounting Method:**

## Unthreaded hole

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

-80.0 collector to base voltage/static/emitter open and -80.0 collector-to-emitter substaining voltage, resistance between base and emitter

# **Current Rating Per Characteristic:**

Between -0.25 amperes source cutoff current and -10.00 amperes source cutoff current

### **Special Features:**

Junction pattern arrangement: pnp

### **Terminal Type And Quantity:**

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

### Fiig:

A110a0